

DG181-DG191

High-Speed Drivers with JFET Switch

The DG181 thru DG191 series of analog gates consist of 2 or 4 N-channel junction-type field-effect transistors (JFET) designed to function as electronic switches. Level-shifting drivers enable low-level inputs (0.8V to 2V) to control the ON-OFF state of each switch. The driver is designed to provide a turn-off speed which is faster than turn-on speed, so that break-before-make action is achieved when switching from one channel to another. In the ON state, each switch conducts current equally well in both directions. In the OFF condition, the switches will block voltages up to 20V peak-to-peak. Switch-OFF input-output isolation 50dB at 10MHz, due to the low output impedance of the FET-gate driving circuit.

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
 - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

April 1999

Features

- Constant ON resistance, $R_{DS(on)}$, to $\pm 10V$ (DG182, DG185, DG186, DG187), to $\pm 7.5V$ (All Devices)
- $\pm 15V$ Power Supplies
- <2nA Leakage from Signal Channel in Both ON and OFF States
- TTL, DTL, RTL Direct Drive Compatibility
- $t_{ON}, t_{OFF} < 150ns$, Break-Before-Make Action
- Cross-Talk and Open Switch Isolation >50dB at 10MHz (75Ω Load)

OBSOLETE PRODUCT
POSSIBLE SUBSTITUTE PRODUCT
DG184, DG185: HI-5049, HI-5045
DG190: DG403, HI-5051, IH5151
DG191: HI-5043, HI-0390, IH5043

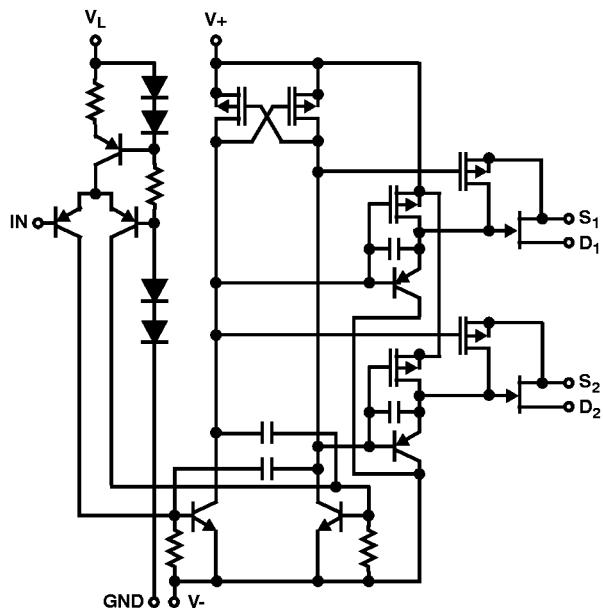
High-Speed Drivers with JFET Switch

Description

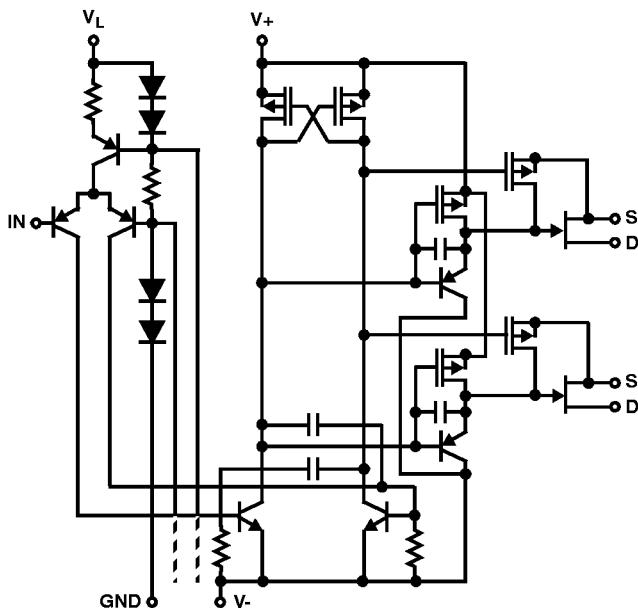
The DG181 thru DG191 series of analog gates consist of 2 or 4 N-channel junction-type field-effect transistors (JFET) designed to function as electronic switches. Level-shifting drivers enable low-level inputs (0.8V to 2V) to control the ON-OFF state of each switch. The driver is designed to provide a turn-off speed which is faster than turn-on speed, so that break-before-make action is achieved when switching from one channel to another. In the ON state, each switch conducts current equally well in both directions. In the OFF condition, the switches will block voltages up to 20V peak-to-peak. Switch-OFF input-output isolation 50dB at 10MHz, due to the low output impedance of the FET-gate driving circuit.

Functional Diagrams (Typical Channel)

DG186, DG187, DG188 - ONE AND TWO CHANNEL SPDT AND SPST CIRCUIT CONFIGURATION



DG183, DG184, DG185 - TWO CHANNEL DPST CIRCUIT CONFIGURATION



DG181 Series

Part Number Information

PART NUMBER	TYPE	R _{DS(ON)} (MAX)	PACKAGE
DG181AA	Dual SPST	30Ω	10 Lead CAN
DG181AA/883B	Dual SPST	30Ω	10 Lead CAN
DG181AP	Dual SPST	30Ω	14 Lead SBDIP
DG181AP/883B	Dual SPST	30Ω	14 Lead SBDIP
DG181BA	Dual SPST	30Ω	10 Lead CAN
DG181BP	Dual SPST	30Ω	14 Lead SBDIP
DG182AA	Dual SPST	75Ω	10 Lead CAN
DG182AA/883B	Dual SPST	75Ω	10 Lead CAN
DG182AP	Dual SPST	75Ω	14 Lead SBDIP
DG182AP/883B	Dual SPST	75Ω	14 Lead SBDIP
DG182BA	Dual SPST	75Ω	10 Lead CAN
DG182BP	Dual SPST	75Ω	14 Lead SBDIP
DG184AP	Dual DPST	30Ω	16 Lead SBDIP
DG184AP/883B	Dual DPST	30Ω	16 Lead SBDIP
DG184BP	Dual DPST	30Ω	16 Lead SBDIP
DG185AP	Dual DPST	75Ω	16 Lead SBDIP
DG185AP/883B	Dual DPST	75Ω	16 Lead SBDIP
DG185BP	Dual DPST	75Ω	16 Lead SBDIP

Part Number Information (Continued)

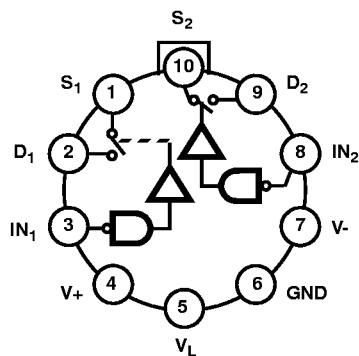
PART NUMBER	TYPE	R _{DS(ON)} (MAX)	PACKAGE
DG187AA	SPDT	30Ω	10 Lead CAN
DG187AA/883B	SPDT	30Ω	10 Lead CAN
DG187AP	SPDT	30Ω	14 Lead SBDIP
DG187AP/883B	SPDT	30Ω	14 Lead SBDIP
DG187BA	SPDT	30Ω	10 Lead CAN
DG187BP	SPDT	30Ω	14 Lead SBDIP
DG188AA	SPDT	75Ω	10 Lead CAN
DG188AA/883B	SPDT	75Ω	10 Lead CAN
DG188AP	SPDT	75Ω	14 Lead SBDIP
DG188AP/883B	SPDT	75Ω	14 Lead SBDIP
DG188BA	SPDT	75Ω	10 Lead CAN
DG188BP	SPDT	75Ω	14 Lead SBDIP
DG190AP	Dual SPDT	30Ω	16 Lead SBDIP
DG190AP/883B	Dual SPDT	30Ω	16 Lead SBDIP
DG190BP	Dual SPDT	30Ω	16 Lead SBDIP
DG191AP	Dual SPDT	75Ω	16 Lead SBDIP
DG191AP/883B	Dual SPDT	75Ω	16 Lead SBDIP
DG191BP	Dual SPDT	75Ω	16 Lead SBDIP

Pinouts and Switching State Diagrams

DUAL SPST - DG181, DG182

(TO-100 METAL CAN)

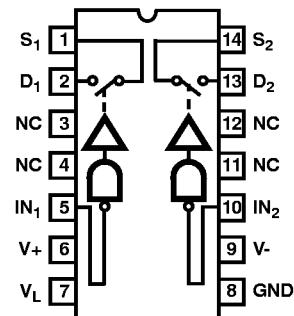
TOP VIFW



DUAL SPST - DG181, DG182

(CDIP)

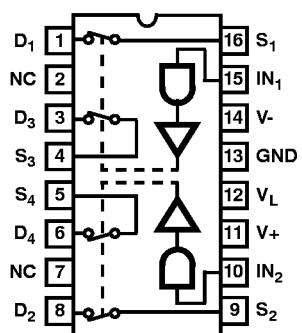
(CBH)
TOP VIEW



DUAL DPST - DG184, DG185

31 - Date
(CDIP)

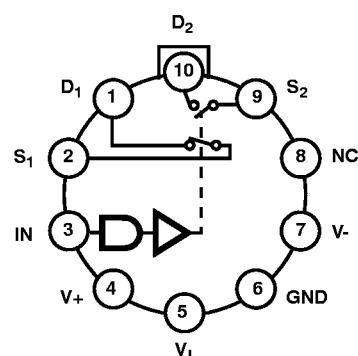
TOP VIEW



SPDT - DG187, DG188

**SPDT - BG15, BG16
(TO-100 METAL CAN)**

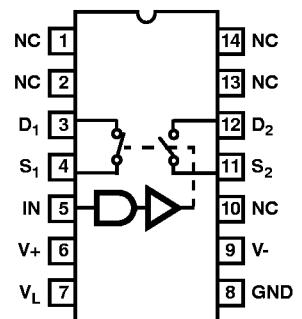
TOP VIEW



SPDT - DG187, DG188

(CDIP)

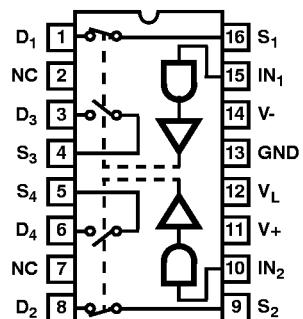
TOP VIEW



DUAL SPDT - DG190, DG191

(CDIP)

TOP VIEW



DG181 Series

Absolute Maximum Ratings

V ₊ - V ₋	36V
V ₊ - V _D	33V
V _D - V ₋	33V
V _D - V _S	±22V
V _L - V ₋	36V
V _L - V _{IN} , V _L - GND, V _{IN} - GND.....	8V
GND - V ₋	27V
GND - V _{IN}	20V
Current (S or D) (Note 3).....	200mA
Storage Temperature.....	-65°C to +150°C
Lead Temperature (Soldering, 10s).....	+300°C

Thermal Information

Operating Temperature.....	-55°C to +125°C
Maximum Power Dissipation †	
TO Metal Can Packages	450mW
Ceramic DIP Packages	825mW

Derate 6mW/°C above +75°C
Derate 11mW/°C above +75°C

† Device mounted with all leads welded or soldered to PC board.

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Electrical Specifications

V₊ = +15V, V₋ = -15V, V_L = 5V, Unless Otherwise Specified

PARAMETER	DEVICE NUMBER	(NOTE 1) TEST CONDITIONS	A SERIES			B SERIES			UNITS
			-55°C	+25°C	+125°C	-20°C	+25°C	+85°C	
SWITCH									
I _{S(OFF)}	DG181, DG182, DG184, DG185, DG187, DG188, DG190, DG191	V _S = 10V, V _D = -10V, V ₊ = 10V, V ₋ = -20V, V _{IN} = "OFF"	-	±1	100	-	±5	100	nA
	DG181, DG184, DG187, DG190	V _S = 7.5V, V _D = -7.5V, V _{IN} = "OFF"	-	±1	100	-	±5	100	nA
	DG182, DG185, DG188, DG191	V _S = 10V, V _D = -10V, V _{IN} = "OFF"	-	±1	100	-	±5	100	nA
I _{D(OFF)}	DG181, DG182, DG184, DG185, DG187, DG188, DG190, DG191	V _S = 10V, V _D = -10V, V ₊ = 10V, V ₋ = -20V, V _{IN} = "OFF"	-	±1	100	-	±5	100	nA
	DG181, DG184, DG187, DG190	V _S = 7.5V, V _D = -7.5V, V _{IN} = "OFF"	-	±1	100	-	±5	100	nA
	DG182, DG185, DG188, DG191	V _S = 10V, V _D = -10V, V _{IN} = "OFF"	-	±1	100	-	±5	100	nA
I _{D(ON)} + I _{S(ON)}	DG181, DG184, DG187, DG190	V _D = V _S = -7.5V, V _{IN} = "ON"	-	±2	-200	-	-10	-200	nA
	DG182, DG185, DG188, DG191	V _D = V _S = -10V, V _{IN} = "ON"	-	±2	-200	-	-10	-200	nA
INPUT									
I _{INL}	All	V _{IN} = 0V	-250	-250	-250	-250	-250	-250	µA
I _{INH}	All	V _{IN} = 5V	-	10	20	-	10	20	µA
DYNAMIC									
t _{ON}	30Ω Switches	See Switching Time Test Circuit	-	150	-	-	180	-	ns
	75Ω Switches		-	250	-	-	300	-	ns
t _{OFF}	30Ω and 75Ω Switches		-	130	-	-	150	-	ns
C _{S(OFF)}	DG181, DG182, DG184, DG185, DG187, DG188, DG190, DG191	V _S = -5V, I _D = 0, f = 1MHz	9 Typical						pF
		V _D = +5V, I _S = 0, f = 1MHz	6 Typical						pF
C _{D(ON)} + C _{S(ON)}		V _D = V _S = 0, f = 1MHz	14 Typical						pF
		R _L = 75Ω, C _L = 3pF	Typically >50dB at 10MHz						-

DG181 Series

Electrical Specifications V₊ = +15V, V₋ = -15V, V_L = 5V, Unless Otherwise Specified (Continued)

PARAMETER	DEVICE NUMBER	(NOTE 1) TEST CONDITIONS	A SERIES			B SERIES			UNITS
			-55°C	+25°C	+125°C	-20°C	+25°C	+85°C	
SUPPLY									
I ₊	DG181, DG182, DG190, DG191	V _{IN} = 5V	-	1.5	-	-	1.5	-	mA
	DG184, DG185		-	0.1	-	-	0.1	-	mA
	DG187, DG188		-	0.8	-	-	0.8	-	mA
I ₋	DG181, DG182, DG190, DG191		-	-5.0	-	-	-5.0	-	mA
	DG184, DG185		-	-4.0	-	-	-4.0	-	mA
	DG187, DG188		-	-3.0	-	-	-3.0	-	mA
I _L	DG181, DG182, DG184, DG185, DG190, DG191		-	4.5	-	-	4.5	-	mA
	DG187, DG188		-	3.2	-	-	3.2	-	mA
I _{GND}	All		-	-2.0	-	-	-2.0	-	mA
I ₊	DG181, DG182, DG190, DG191	V _{IN} = 0V	-	1.5	-	-	1.5	-	mA
	DG184, DG185		-	3.0	-	-	3.0	-	mA
	DG187, DG188		-	0.8	-	-	0.8	-	mA
I ₋	DG181, DG182, DG190, DG191		-	-5.0	-	-	-5.0	-	mA
	DG184, DG185		-	-5.5	-	-	-5.5	-	mA
	DG187, DG188		-	-3.0	-	-	-3.0	-	mA
I _L	DG181, DG182, DG184, DG185, DG190, DG191		-	4.5	-	-	4.5	-	mA
	DG187, DG188		-	3.2	-	-	3.2	-	mA
I _{GND}	All		-	-2.0	-	-	-2.0	-	mA

NOTE:

1. See Switching State Diagrams for V_{IN} "ON" and V_{IN} "OFF" Test Conditions.

Electrical Specifications Maximum Resistances (R_{DS(ON)} MAX)

DEVICE NUMBER	TEST CONDITIONS (NOTE 1) V ₊ = 15V, V ₋ = -15V, V _L = 5V	I _S = -10mA, V _{IN} = "ON"	MILITARY TEMPERATURE			INDUSTRIAL TEMPERATURE			UNITS
			-55°C	+25°C	+125°C	-20°C	+25°C	+85°C	
DG181	V _D = -7.5V		30	30	60	50	50	75	Ω
DG182	V _D = -10V		75	75	100	100	100	150	Ω
DG184	V _D = -7.5V		30	30	60	50	50	75	Ω
DG185	V _D = -10V		75	75	150	100	100	150	Ω
DG187	V _D = -7.5V		30	30	60	50	50	75	Ω
DG188	V _D = -10V		75	75	150	100	100	150	Ω
DG190	V _D = -7.5V		30	30	60	50	50	75	Ω
DG191	V _D = -10V		75	75	150	100	100	150	Ω

NOTES:

1. See Switching State Diagrams for V_{IN} "ON" and V_{IN} "OFF" Test Conditions.
2. Normally the minimum signal handling capability of the DG181 thru DG191 family is 20V peak to peak for the 75Ω switches and 15V peak-to-peak for the 30Ω (refer I_D and I_S tests above).
3. For other Analog Signals, the following guidelines can be used: proper switch turn-off requires that V₋ ≤ V_{ANALOG(peak)} - V_P where V_P = 7.5V for the 80Ω switches and V_P = 5.0V for 75Ω switches e.g., -10V minimum (-peak) analog signal and a 75Ω switch (V_P = 5V), requires that V₋ ≤ -10V - 5V = -15V.

DUAL SPST - DG181/182

TEST CONDITIONS	
V_{IN} "ON" = 0.8V	All Channels
V_{IN} "OFF" = 2.0V	All Channels

NOTE:

1. Switch states are for logic "1" input = 2.0V.

SPDT - DG187/188

TEST CONDITIONS	
V_{IN} "ON" = 2.0V	Channel 1
V_{IN} "ON" = 0.8V	Channel 2
V_{IN} "OFF" = 2.0V	Channel 2
V_{IN} "OFF" = 0.8V	Channel 1

NOTE:

1. Switch states are for logic "1" input = 2.0V.

DUAL DPST - DG184/185

TEST CONDITIONS	
V_{IN} "ON" = 2.0V	All Channels
V_{IN} "OFF" = 0.8V	All Channels

NOTE:

1. Switch states are for logic "1" input = 2.0V.

SPDT - DG190/191

TEST CONDITIONS	
V_{IN} "ON" = 2.0V	Channel 1 and 2
V_{IN} "ON" = 0.8V	Channel 3 and 4
V_{IN} "OFF" = 2.0V	Channel 3 and 4
V_{IN} "OFF" = 0.8V	Channel 1 and 2

NOTE:

1. Switch states are for logic "1" input = 2.0V.

Switching Time Test Circuits

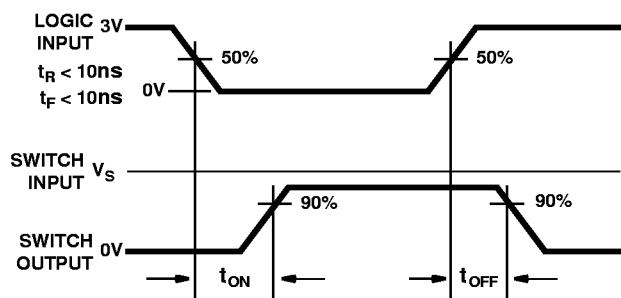


FIGURE 1. SWITCHING TIME TEST WAVEFORMS (Note 1)

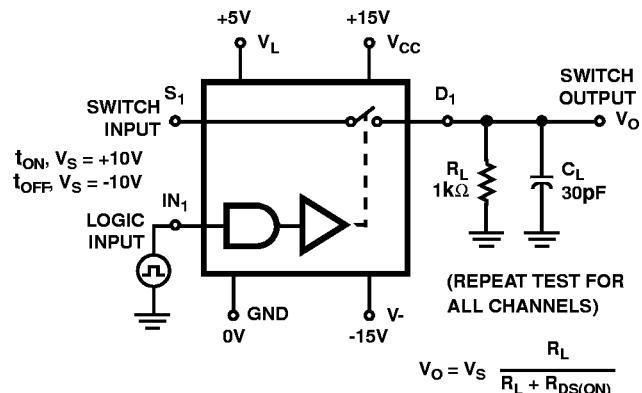
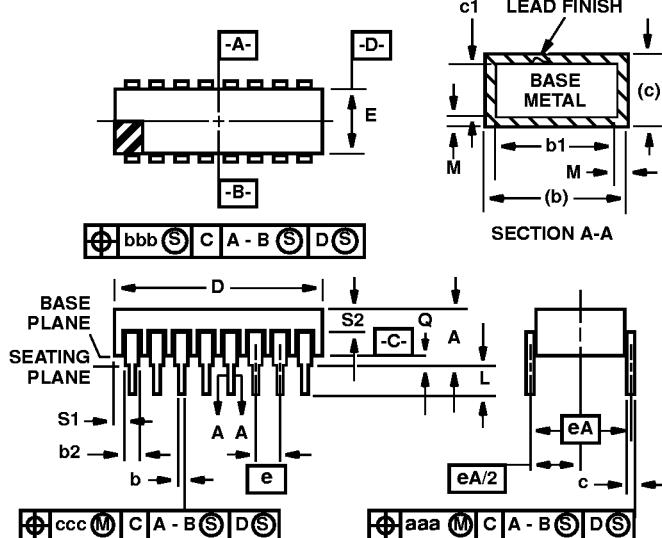


FIGURE 2. SWITCHING TIME TEST CIRCUIT (Note 2)

NOTES:

1. Switch output waveform shown for V_S = constant with logic input waveform as shown.
2. V_S may be + or - as per switching time test circuit. V_O is the steady state output with switch on. Feedthrough via gate capacitance may result in spikes at leading and trailing edge of output waveform.

Ceramic Dual-In-Line Metal Seal Packages (SBDIP)



NOTES:

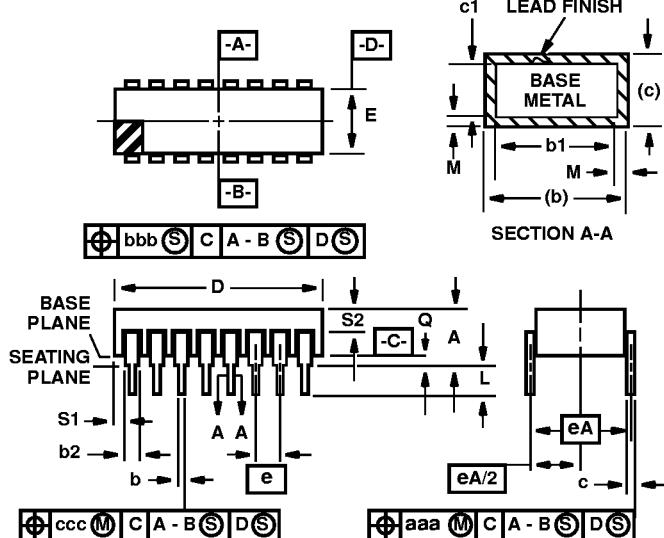
1. Index area: A notch or a pin one identification mark shall be located adjacent to pin one and shall be located within the shaded area shown. The manufacturer's identification shall not be used as a pin one identification mark.
2. The maximum limits of lead dimensions b and c or M shall be measured at the centroid of the finished lead surfaces, when solder dip or tin plate lead finish is applied.
3. Dimensions b1 and c1 apply to lead base metal only. Dimension M applies to lead plating and finish thickness.
4. Corner leads (1, N, N/2, and N/2+1) may be configured with a partial lead paddle. For this configuration dimension b3 replaces dimension b2.
5. Dimension Q shall be measured from the seating plane to the base plane.
6. Measure dimension S1 at all four corners.
7. Measure dimension S2 from the top of the ceramic body to the nearest metallization or lead.
8. N is the maximum number of terminal positions.
9. Braze fillets shall be concave.
10. Dimensioning and tolerancing per ANSI Y14.5M - 1982.
11. Controlling dimension: INCH.

D14.3 MIL-STD-1835 CDIP2-T14 (D-1, CONFIGURATION C)
14 LEAD CERAMIC DUAL-IN-LINE METAL SEAL PACKAGE

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	-	0.200	-	5.08	-
b	0.014	0.026	0.36	0.66	2
b1	0.014	0.023	0.36	0.58	3
b2	0.045	0.065	1.14	1.65	-
b3	0.023	0.045	0.58	1.14	4
c	0.008	0.018	0.20	0.46	2
c1	0.008	0.015	0.20	0.38	3
D	-	0.785	-	19.94	-
E	0.220	0.310	5.59	7.87	-
e	0.100 BSC		2.54 BSC		-
eA	0.300 BSC		7.62 BSC		-
eA/2	0.150 BSC		3.81 BSC		-
L	0.125	0.200	3.18	5.08	-
Q	0.015	0.060	0.38	1.52	5
S1	0.005	-	0.13	-	6
S2	0.005	-	0.13	-	7
α	90°	105°	90°	105°	-
aaa	-	0.015	-	0.38	-
bbb	-	0.030	-	0.76	-
ccc	-	0.010	-	0.25	-
M	-	0.0015	-	0.038	2
N	14		14		8

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Ceramic Dual-In-Line Metal Seal Packages (SBDIP)



NOTES:

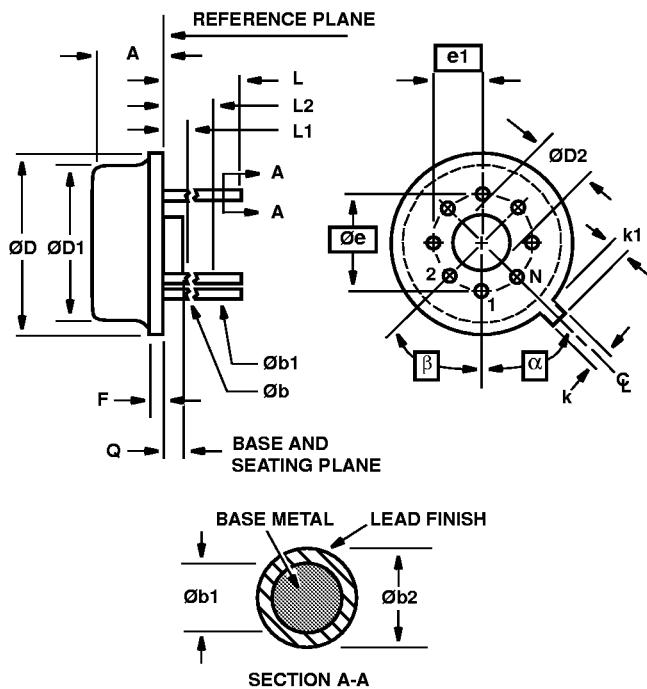
1. Index area: A notch or a pin one identification mark shall be located adjacent to pin one and shall be located within the shaded area shown. The manufacturer's identification shall not be used as a pin one identification mark.
2. The maximum limits of lead dimensions b and c or M shall be measured at the centroid of the finished lead surfaces, when solder dip or tin plate lead finish is applied.
3. Dimensions b_1 and c_1 apply to lead base metal only. Dimension M applies to lead plating and finish thickness.
4. Corner leads (1, N, $N/2$, and $N/2+1$) may be configured with a partial lead paddle. For this configuration dimension b_3 replaces dimension b_2 .
5. Dimension Q shall be measured from the seating plane to the base plane.
6. Measure dimension S_1 at all four corners.
7. Measure dimension S_2 from the top of the ceramic body to the nearest metallization or lead.
8. N is the maximum number of terminal positions.
9. Braze fillets shall be concave.
10. Dimensioning and tolerancing per ANSI Y14.5M - 1982.
11. Controlling dimension: INCH.

**D16.3 MIL-STD-1835 CDIP2-T16 (D-2, CONFIGURATION C)
16 LEAD CERAMIC DUAL-IN-LINE METAL SEAL PACKAGE**

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	-	0.200	-	5.08	-
b	0.014	0.026	0.36	0.66	2
b_1	0.014	0.023	0.36	0.58	3
b_2	0.045	0.065	1.14	1.65	-
b_3	0.023	0.045	0.58	1.14	4
c	0.008	0.018	0.20	0.46	2
c_1	0.008	0.015	0.20	0.38	3
D	-	0.840	-	21.34	-
E	0.220	0.310	5.59	7.87	-
e	0.100 BSC		2.54 BSC		-
eA	0.300 BSC		7.62 BSC		-
$eA/2$	0.150 BSC		3.81 BSC		-
L	0.125	0.200	3.18	5.08	-
Q	0.015	0.060	0.38	1.52	5
S_1	0.005	-	0.13	-	6
S_2	0.005	-	0.13	-	7
α	90°	105°	90°	105°	-
aaa	-	0.015	-	0.38	-
bbb	-	0.030	-	0.76	-
ccc	-	0.010	-	0.25	-
M	-	0.0015	-	0.038	2
N	16		16		8

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Metal Can Packages (Can)



NOTES:

- (All leads) $\varnothing b$ applies between L1 and L2. $\varnothing b_1$ applies between L2 and 0.500 from the reference plane. Diameter is uncontrolled in L1 and beyond 0.500 from the reference plane.
- Measured from maximum diameter of the product.
- α is the basic spacing from the centerline of the tab to terminal 1 and β is the basic spacing of each lead or lead position (N -1 places) from α , looking at the bottom of the package.
- N is the maximum number of terminal positions.
- Dimensioning and tolerancing per ANSI Y14.5M - 1982.
- Controlling dimension: INCH.

T10.B MIL-STD-1835 MACY1-X10 (A2)
10 LEAD METAL CAN PACKAGE

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	0.165	0.185	4.19	4.70	-
$\varnothing b$	0.016	0.019	0.41	0.48	1
$\varnothing b_1$	0.016	0.021	0.41	0.53	1
$\varnothing b_2$	0.016	0.024	0.41	0.61	-
$\varnothing D$	0.335	0.375	8.51	9.52	-
$\varnothing D_1$	0.305	0.335	7.75	8.51	-
$\varnothing D_2$	0.110	0.160	2.79	4.06	-
e	0.230 BSC		5.84 BSC		-
e1	0.115 BSC		2.92 BSC		-
F	-	0.040	-	1.02	-
k	0.027	0.034	0.69	0.86	-
k1	0.027	0.045	0.69	1.14	2
L	0.500	0.750	12.70	19.05	1
L1	-	0.050	-	1.27	1
L2	0.250	-	6.35	-	1
Q	0.010	0.045	0.25	1.14	-
α	36° BSC		36° BSC		3
β	36° BSC		36° BSC		3
N	10		10		4

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